



Radiation hardness by design for mixed signal infrared readout circuit applications

Stephen D. Gaalema, Dave Dobyms,
James Gates, Greg Pauls, Bruce Wall

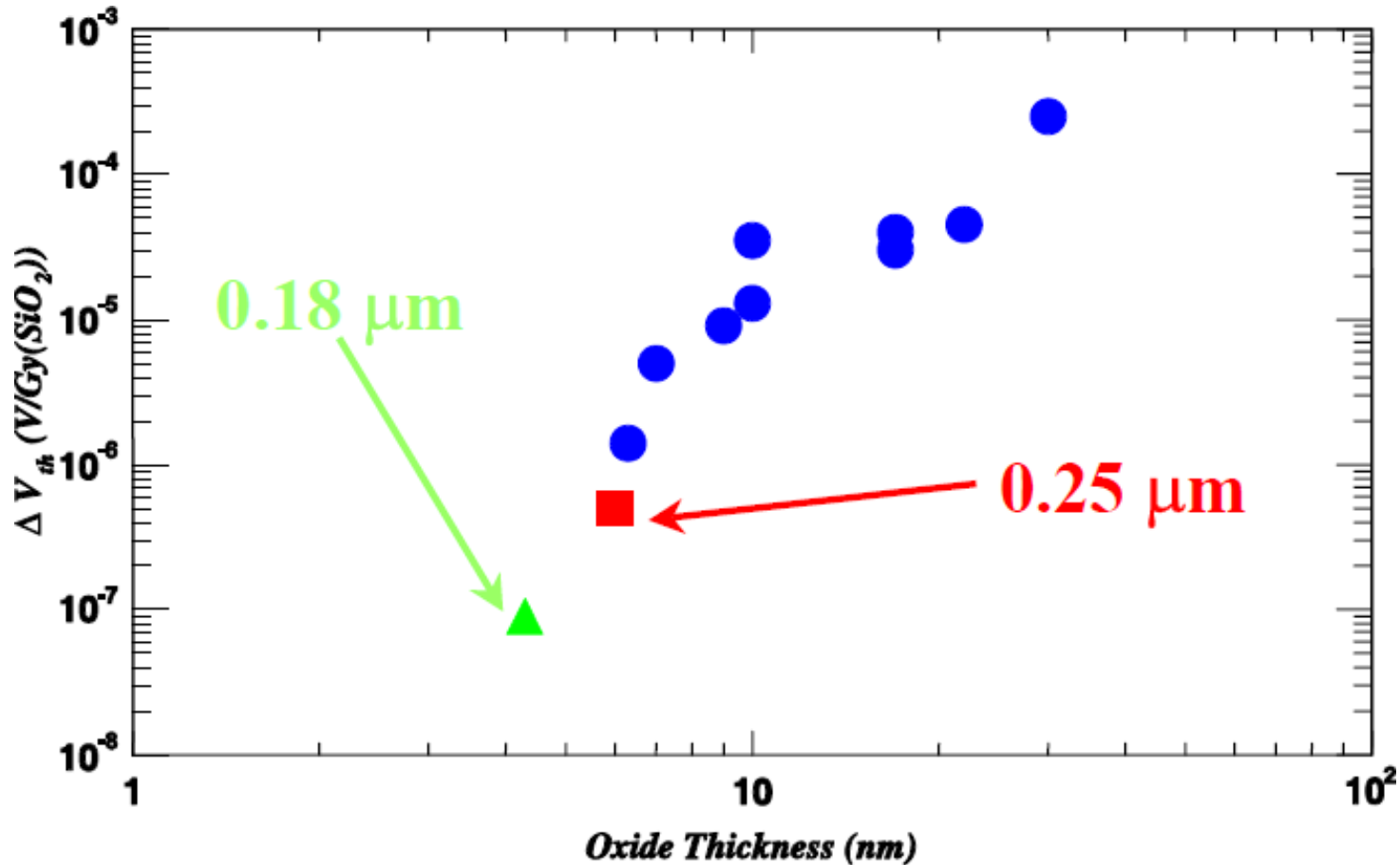
Black Forest Engineering, LLC, 9348 Grand Cordera Parkway,
Colorado Springs, CO 80924, USA

Mixed Signal RHBD Presentation Overview



- Radiation tolerant ROICs to support space-based infrared detection applications
- Radiation Hardening by Design (RHBD) methodology
- Appl. #1: Thermopile ROIC for mission to Europa
- Appl. #2: LWIR PV ROIC for spaced based sensing
- ROIC RHBD Capability and Conclusions

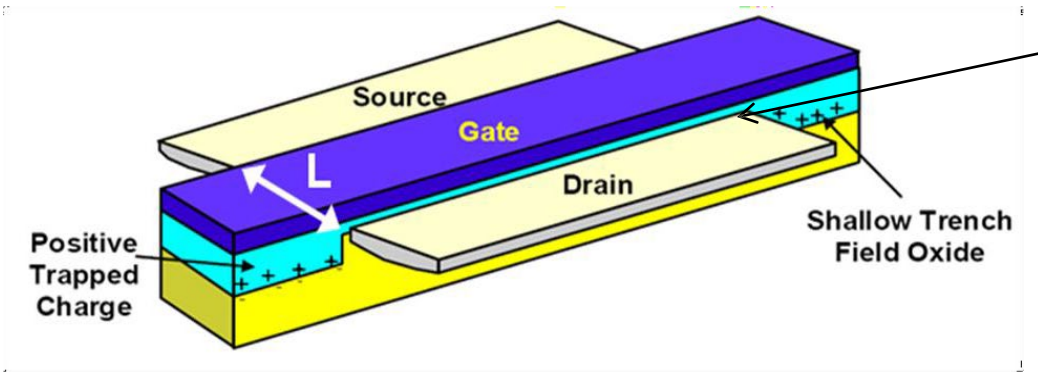
FET $\Delta V_{th}/TID$ versus gate oxide thickness -huge advantage for gate oxide thickness reduction



IEEE Trans. on Nuclear Science, Vol. 52, pp. 861-867 (2005).

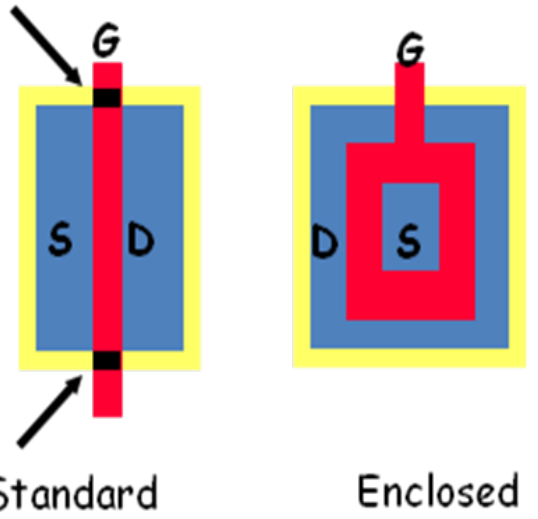
NFETS still not radiation tolerant

-Enclosed NFETS provide large TID immunity-



NFET parasitic channel at STI
-increased leakage current
-increased 1/f noise-

Leakage path



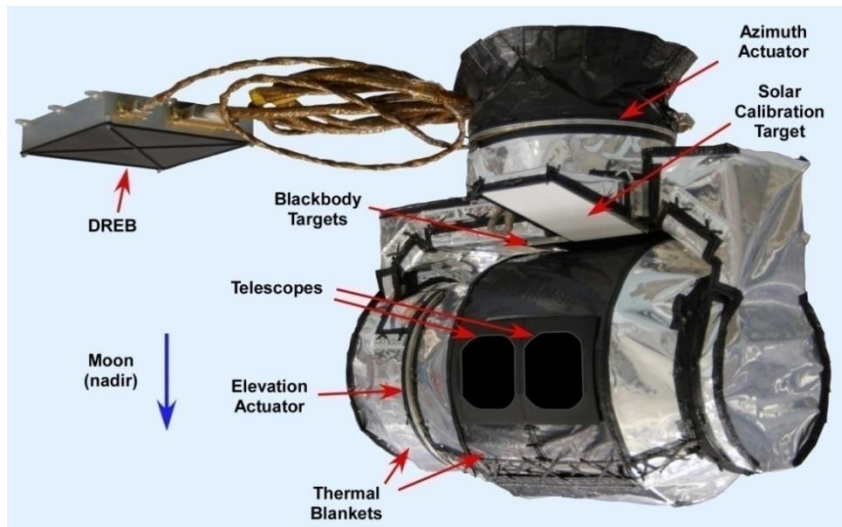
Top view layout comparison
standard and enclosed (annular gate) FETs

ROIC RHBD Methodology

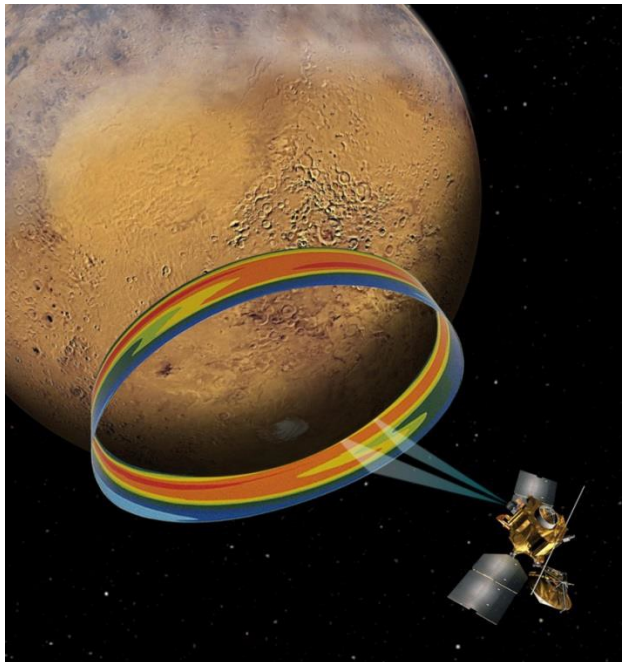


1. Thin gate oxide (<math><4.5\text{ nm}</math>) FETs for both analog and digital circuitry to reduce TID related threshold voltage shift
2. Annular/enclosed gate NFETS to reduce TID dose related off current, maintain low $1/f$ noise, and provide long term reliability
3. Circuit biasing and design to compensate for total ionizing dose
4. Guard rings and low resistance well contacts to prevent latch up
5. Optimized ROIC circuitry to provide high S/N and operability in a high radiation environment (total dose and dose rate)

BFE Thermopile ROICs support prior NASA Missions (NASA/JPL Thermopile linear IR array and BFE CMOS readout)

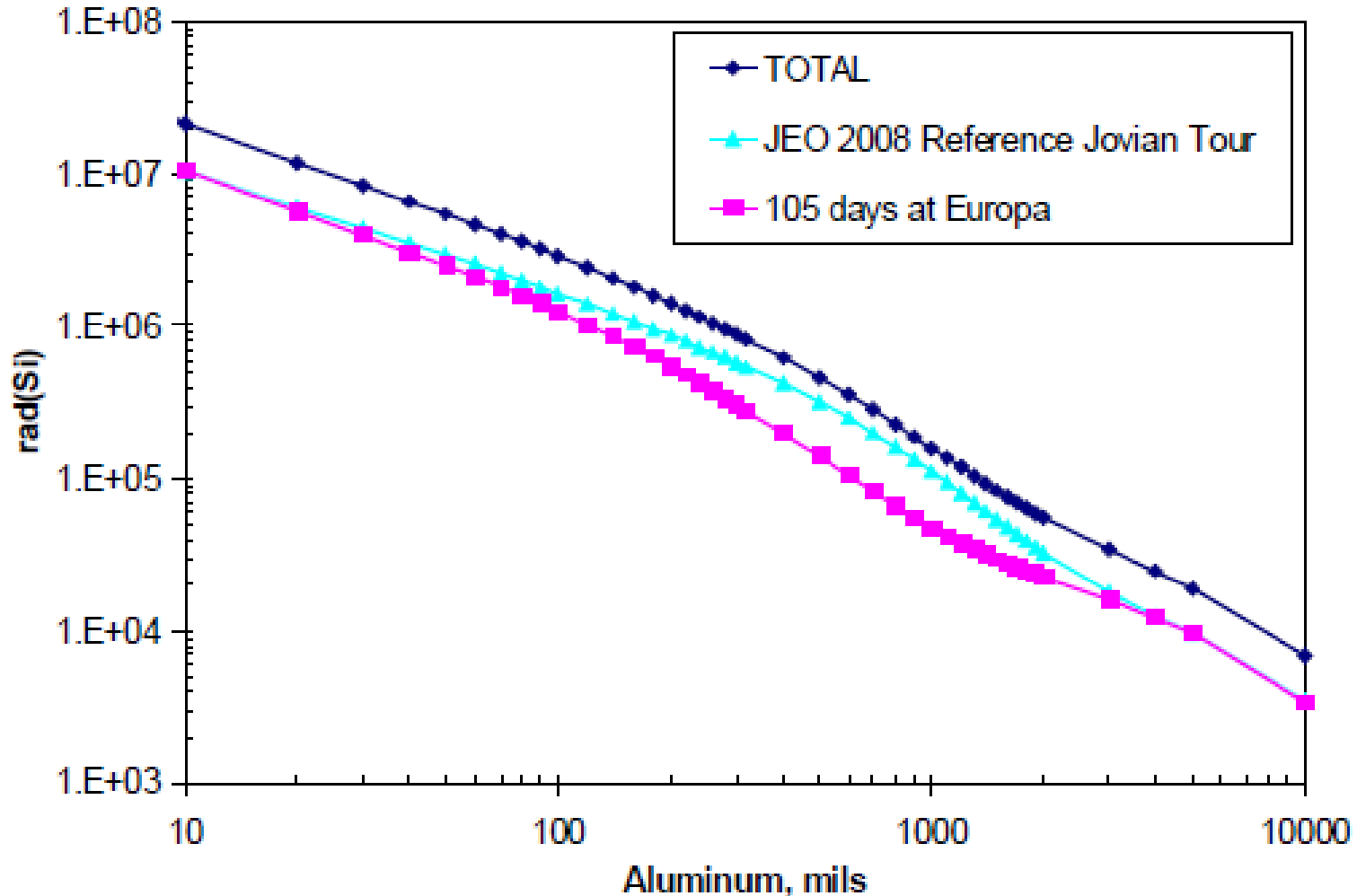


Diviner Lunar Radiometer Experiment
(Launched 18 June 2009)



Mars Climate Sounder is one
instrument on the Mars
Reconnaissance Orbiter Spacecraft,
launched August 12, 2005,

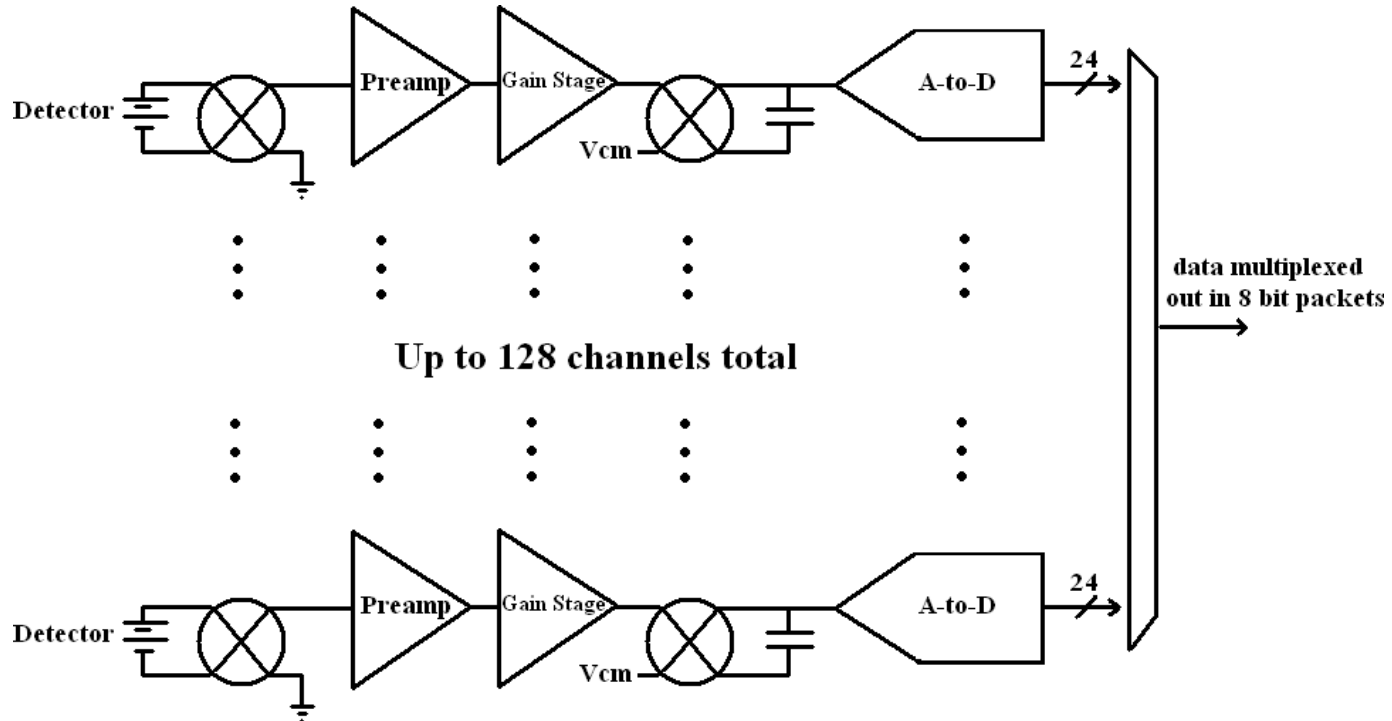
Future missions may need "rad-hard" ROIC - Example prior JEO mission concept-



JEO 2008 conceptual mission study JPL D-48256

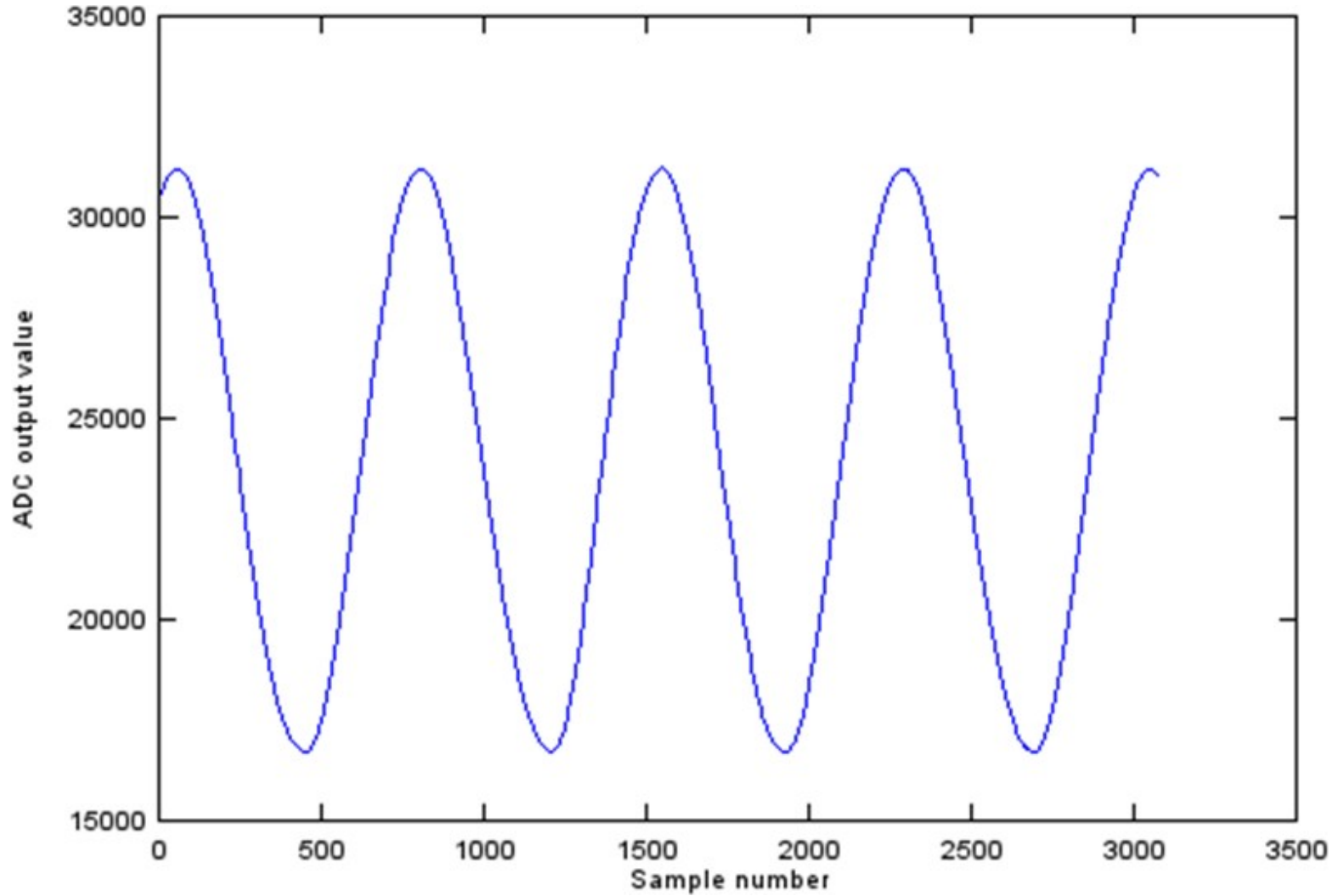
Note: Recent Europa Clipper mission concept has reduced TID requirements

BFE333 RHBD ROIC for Thermopile Linear Arrays

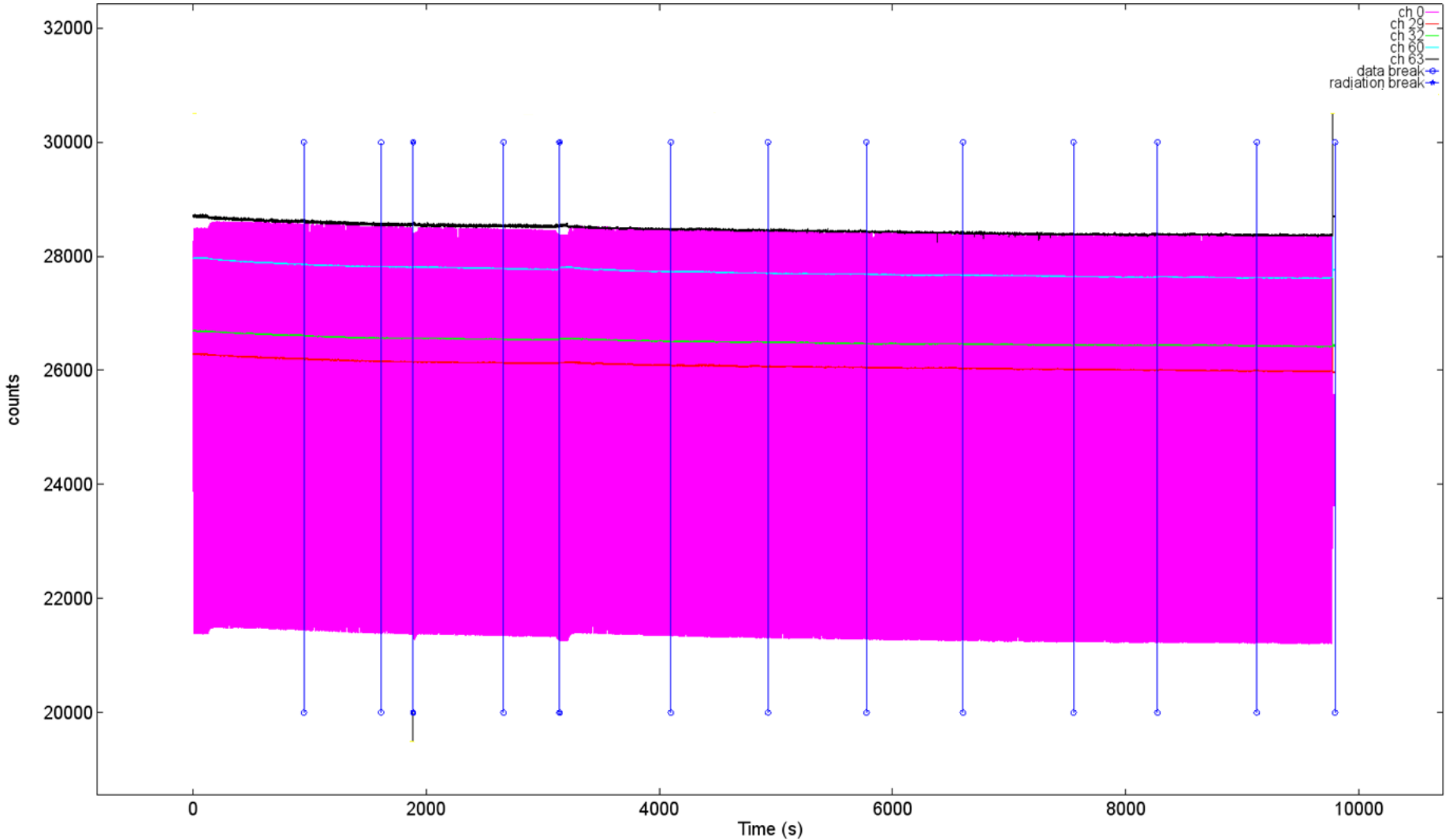


- 110 μm channel pitch, < 1 mW/channel
- Requires 2 bond pads per thermopile (improved S/N, polarity switching)
 - On-ROIC ADC: 18-bits, LVDS output, system noise immunity
 - Compatible with thermopiles of 10-150k Ω resistance
 - RHBD: 4.5 nm Tox gates, enclosed NFETs, GR's,
 - TID capability > 2 MRad

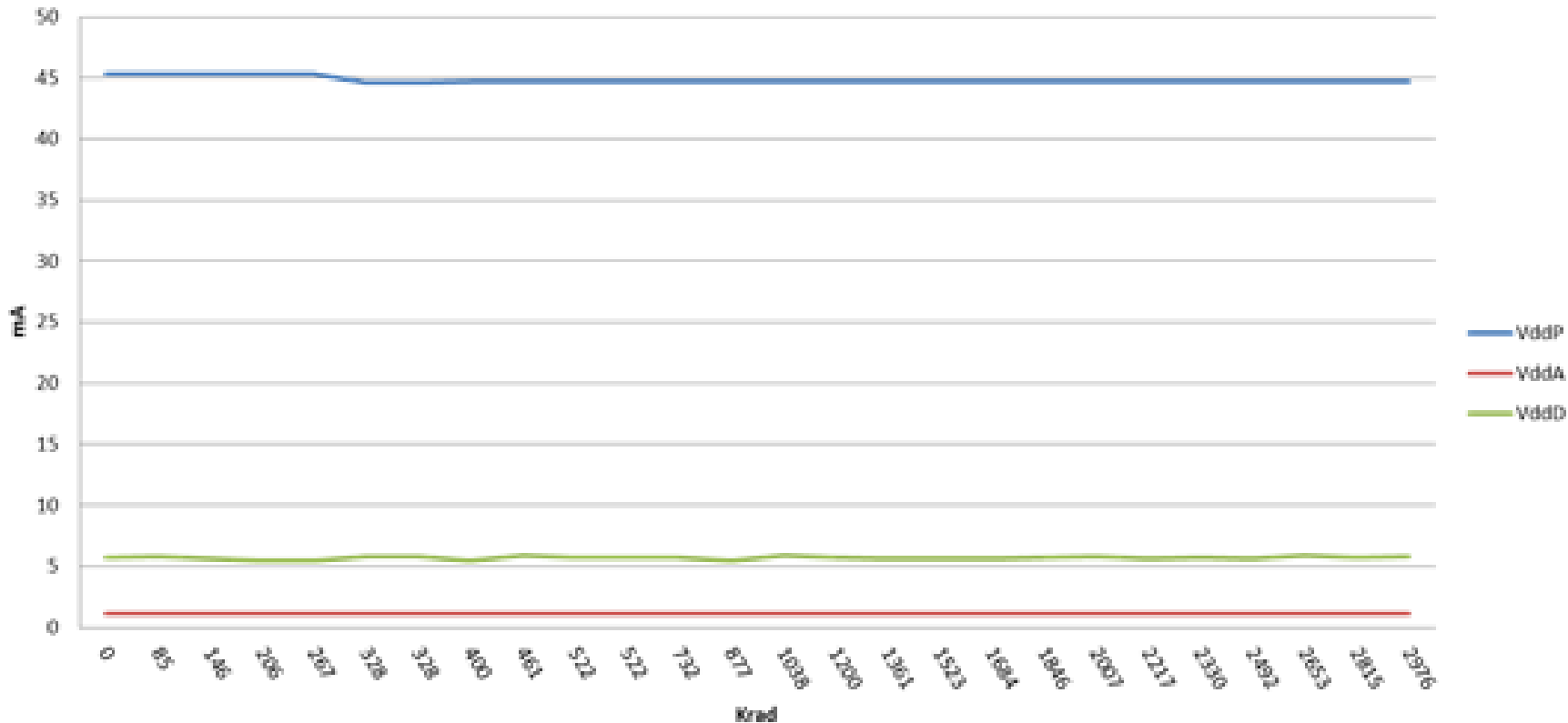
BF E333 ROIC digital output -sine wave electrical input-



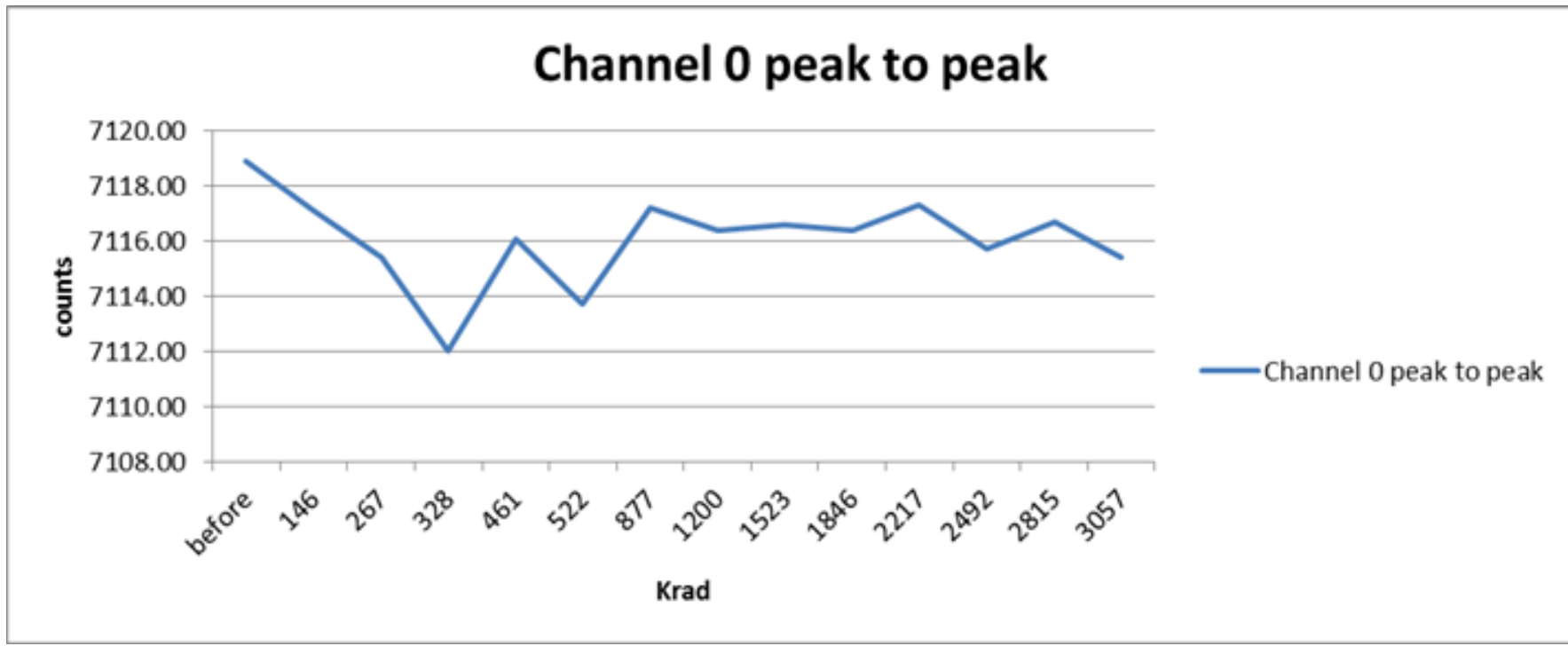
BF333 Raw output during radiation test



Measured dc supply currents (VddP, VddA and VddD) versus TID in kRad



Channel 0 signal amplitude ADC counts (1 mV peak to peak sine wave across 10 k Ω resistor)

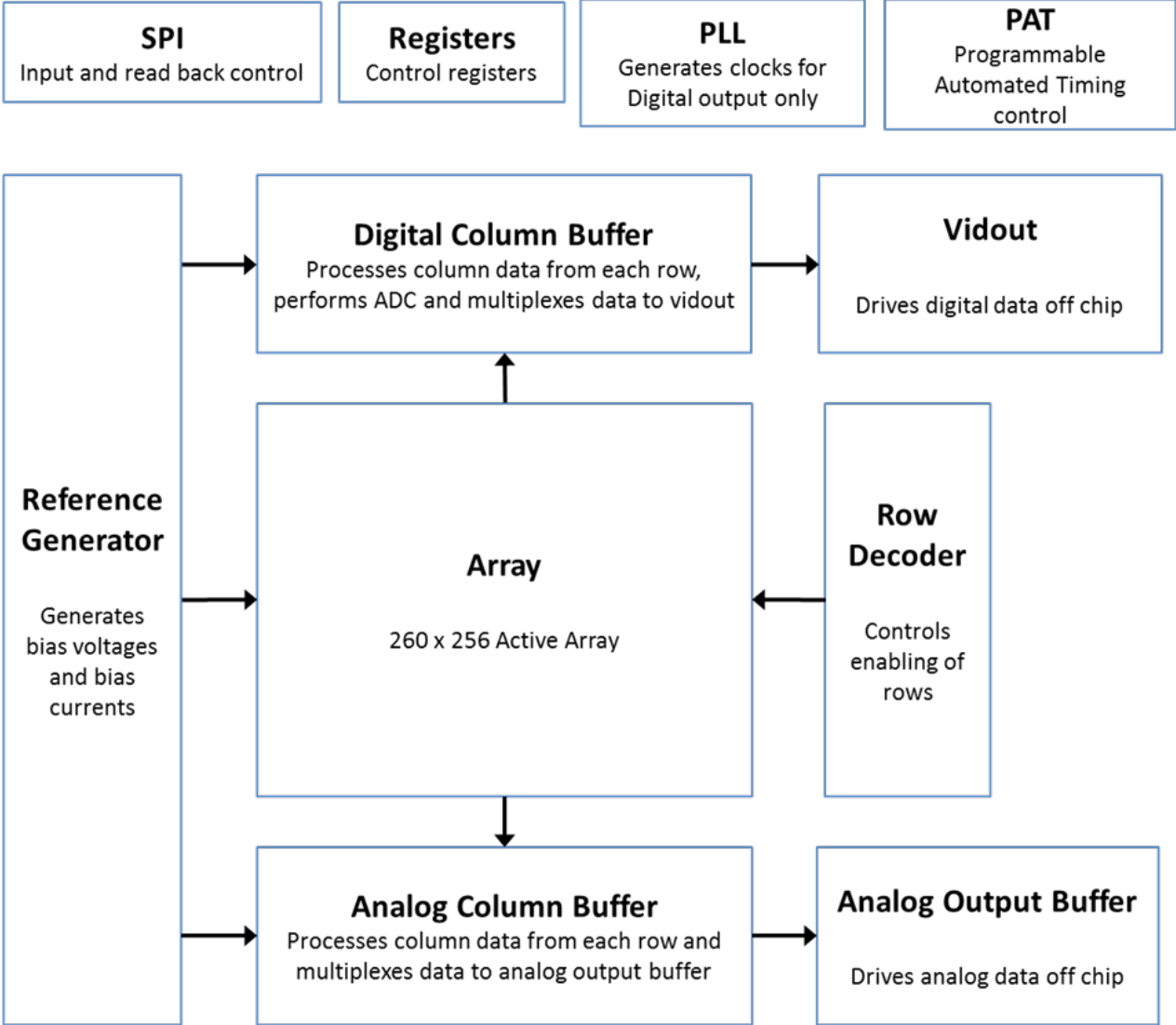


RHBD ROIC for space-based LWIR area arrays



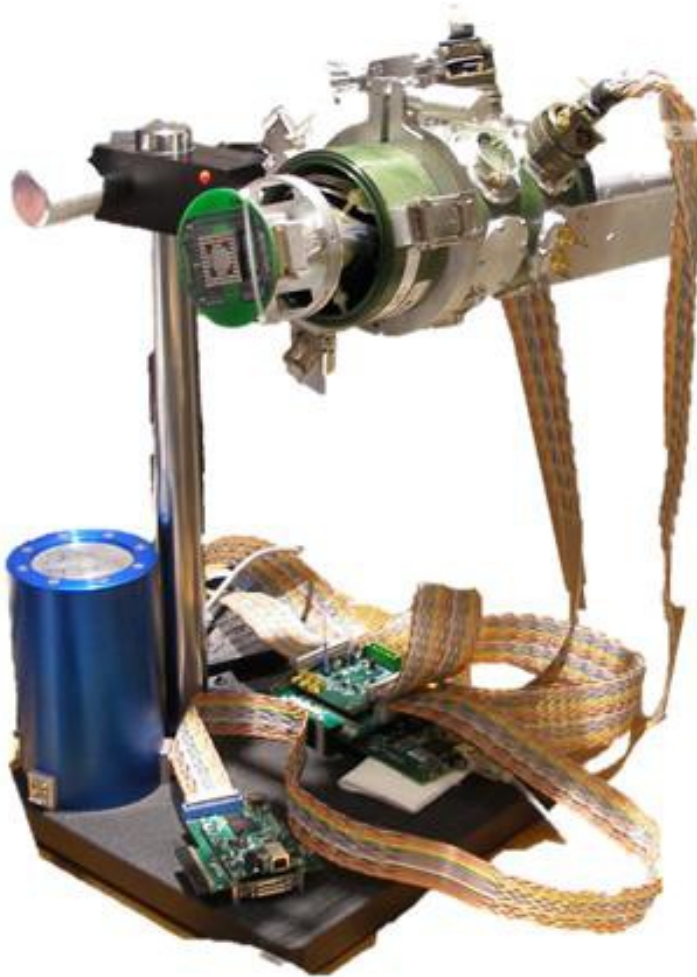
1. ROIC format: 260 x 256 array on a 40 μm pixel pitch
 2. 40-77 K operation temperature
 3. >300 kRad TID capable
 4. Per pixel detector bias optimization
5. CTIA pixel amp, snap-shot, integrate while read, anti-bloom
 6. On-ROIC in-pixel CDS
7. Digital output or multiple analog outputs available
 8. 180 nm CMOS process

BFE315 Simplified block diagram illustrating the overall architecture





Dewar without lid (left), Dewar and harness just before placement in (Cobalt 60) chamber



BFE315 ROIC TID testing 77 K

Slight increase in supply current with TID



ROIC supply currents vs. temperature

Supply	300K mA	76K mA	40K mA
VddP	14.5	11.4	12.0
Vref	0.9	0.9	0.6
VddA	7.2	8.9	7.9
VddO	1.7	1.9	2.2
VddD	73.6	70.8	71.0

Supply currents during ROIC TID test @ 77K

Test number	0	1	2	3	4	5	6	7
Dose (kRad)	0	10	20	50	100	200	300	400
VddP (mA)	12.1	12.1	12.0	12.1	11.8	12.3	12.0	12.1
Vref (mA)	0.9	0.9	0.7	0.8	0.7	0.8	0.9	0.8
VddA (mA)	7.4	7.9	7.3	8.9	8.4	6.3	8.4	8.2
VddO (mA)	2.1	2.4	2.1	2.2	2.3	2.4	2.4	2.3
VddD (mA)	66	66.8	67.0	70.1	66.9	68.3	70.0	82.7

Conclusions and Acknowledgement



1. BFE RHBD approach using 180 nm CMOS achieved \sim 3 Mrad TID for thermopile ROIC and $>$ 400 kRad TID for cryocooled PV ROIC.
2. Use of 130/90 nm CMOS is anticipated to further improve TID tolerance for mixed-signal applications

We thank Matthew Kenyon at NASA JPL and Vincent Cowan at AFRL for their support of this work under SBIR Contract Number: NNX10CE04P titled "Thermopile Detector Radiation Hardened Readout" and Contract Number W9113M-10-C-0068 titled "Design Modified Commercial CMOS for MDA IR FPAs" respectively.